

# isc Silicon PNP Power Transistor

2SA1232

#### **DESCRIPTION**

- · Collector-Emitter Breakdown Voltage-
  - : V<sub>(BR)CEO</sub>= -130V(Min)
- · Good Linearity of hFE
- Complement to Type 2SC3012
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

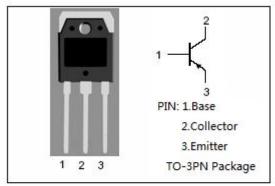


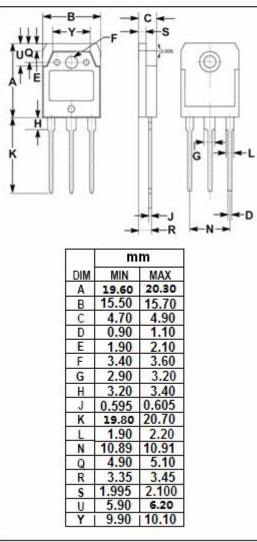
### **APPLICATIONS**

• For audio frequency power amplifier applications.

### ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

| SYMBOL           | PARAMETER  | VALUE | UNIT       |  |
|------------------|--|-------|------------|--|
| V <sub>СВО</sub> | Collector-Base Voltage                             | -130  | V          |  |
| Vceo             | Collector-Emitter Voltage                          | -130  | ٧          |  |
| $V_{EBO}$        | Emitter-Base Voltage                               | -5    | V          |  |
| lc               | Collector Current-Continuous                       | -10   | Α          |  |
| Ісм              | Collector Current-Peak                             | -15   | Α          |  |
| P <sub>C</sub>   | Collector Power Dissipation @ T <sub>C</sub> =25°C | 100   | W          |  |
| TJ               | Junction Temperature                               | 150   | $^{\circ}$ |  |
| T <sub>stg</sub> | T <sub>stg</sub> Storage Temperature Range         |       | $^{\circ}$ |  |







# isc Silicon PNP Power Transistor

2SA1232

### **ELECTRICAL CHARACTERISTICS**

T<sub>c</sub>=25℃ unless otherwise specified

| 10 20 0 amount of opposition |                                      |   |     |      |      |      |  |
|------------------------------|--------------------------------------|---|-----|------|------|------|--|
| SYMBOL                       | PARAMETER                            | CONDITIONS  | MIN | TYP. | MAX  | UNIT |  |
| V <sub>CE</sub> (sat)        | Collector-Emitter Saturation Voltage | Ic= -5.0A; I <sub>B</sub> = -0.5A                     |     |      | -1.5 | V    |  |
| V <sub>BE</sub> (sat)        | Base-Emitter Saturation Voltage      | I <sub>C</sub> = -5.0A; I <sub>B</sub> = -0.5A        |     |      | -2.0 | V    |  |
| I <sub>CBO</sub>             | Collector Cutoff Current             | V <sub>CB</sub> = -130V; I <sub>E</sub> = 0           |     |      | -50  | μА   |  |
| ІЕВО                         | Emitter Cutoff Current               | V <sub>EB</sub> = -3V; I <sub>C</sub> = 0             |     |      | -50  | μА   |  |
| h <sub>FE-1</sub>            | DC Current Gain                      | I <sub>C</sub> = -2A; V <sub>CE</sub> = -5V           | 60  |      | 320  |      |  |
| h <sub>FE-2</sub>            | DC Current Gain                      | I <sub>C</sub> = -5A; V <sub>CE</sub> = -5V           | 40  |      |      |      |  |
| Сов                          | Output Capacitance                   | I <sub>E</sub> = 0; V <sub>CB</sub> = -10V; f= 1.0MHz |     | 250  |      | pF   |  |
| f <sub>T</sub>               | Current-Gain—Bandwidth Product       | I <sub>C</sub> = -1A; V <sub>CE</sub> = -5V           |     | 60   |      | MHz  |  |

## ♦ h<sub>FE-1</sub> Classifications

| R      | Q       | Р       |
|--------|---------|---------|
| 60-120 | 100-200 | 160-320 |

### **NOTICE:**

ISC reserves the rights to make changes of the content herein the datasheet at any time without notification. The information contained herein is presented only as a guide for the applications of our products.

ISC products are intended for usage in general electronic equipment. The products are not designed for use in equipment which require specialized quality and/or reliability, or in equipment which could have applications in hazardous environments, aerospace industry, or medical field. Please contact us if you intend our products to be used in these special applications. ISC makes no warranty or guarantee regarding the suitability of its products for any particular purpose, nor does ISC assume any liability arising from the application or use of any products, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.